

HIGH SPEED SWITCHING 2A(4Arms)MOLD THYRISTOR **2S2M, 2S3M, 2S4M**

The 2S2M ~ 2S4M are P-gate all diffused mold type SCR granted RMS on-state current 4 Amps and repetitive peak on-state current 15 Amps ($T_c=65^\circ C$, $f=10KPPS$, $t_p=10\mu s$).

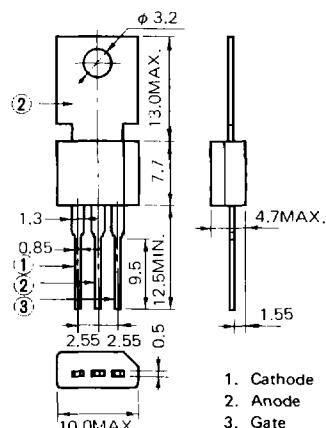
FEATURES

- Designed for Inverter, Pulse modulator, and other high frequency applications.
- Insured turn-off time of less than $15\mu s$.
- $300\mu A$ gate sensitivity
- 200 through 400 V selection

APPLICATIONS

- Automatic gas lighter
- Speed control of miniature type motor
- Electric sewing machine
- Battery charger
- TV
- Solenoid operation
- Inverter

OUTLINE DRAWING (Unit: mm)



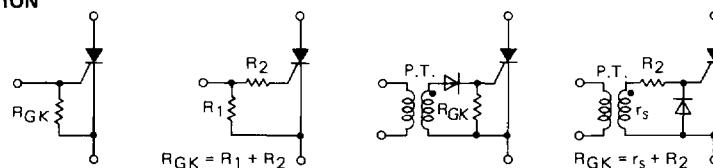
MAXIMUM RATINGS

Item	Symbol	2S2M	2S3M	2S4M	Unit	Note
Non-Repetitive Peak Reverse Voltage	V_{RSM}	300	400	500	V	$R_{GK}=1k\Omega$
Non-Repetitive Peak Off-State Voltage	V_{DSM}	300	400	500	V	$R_{GK}=1k\Omega$
Repetitive Peak Reverse Voltage	V_{RRM}	200	300	400	V	$R_{GK}=1k\Omega$
Repetitive Peak Off-State Voltage	V_{DRM}	200	300	400	V	$R_{GK}=1k\Omega$
On-State Current	$I_{T(AV)}$	$2 (T_c=54^\circ C, \theta=180^\circ \text{ Single phase } 1/2 \text{ wave})$			A	See Fig. 3, Fig. 4
Repetitive Peak On-State Current	I_{TM}	$15 (T_c=65^\circ C, f=10KPPS, t_p=10\mu s)$			A	See Fig. 3, Fig. 4
Surge Non-Repetitive On-State Current	I_{TSM}	20			A	See Fig. 2
Peak Gate Power Dissipation	P_{GM}	$0.5 (f \geq 50 \text{ Hz, duty} \leq 10\%)$			W	
Average Gate Power Dissipation	$P_{G(AV)}$	0.1			W	
Peak Gate Forward Current	I_{FGM}	$0.2 (f \geq 50 \text{ Hz, duty} \leq 10\%)$			A	
Peak Gate Reverse Voltage	V_{RGM}	6			V	
Junction Temperature	T_j	$-40 \sim +110$			$^\circ C$	
Storage Temperature	T_{stg}	$-40 \sim +150$			$^\circ C$	
Weight		1.4			g	

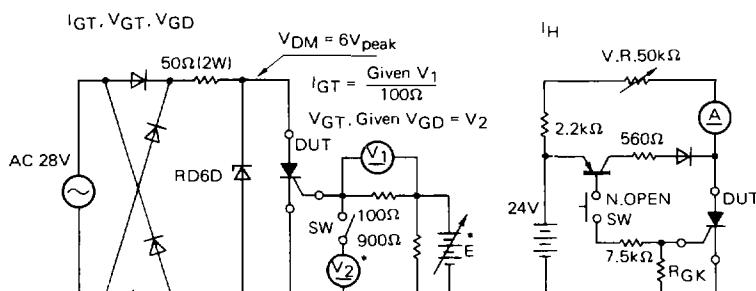
T_c : Case Temperature is measured at 1.5mm from the neck of Tablet.

CHARACTERISTICS ($T_j=25^\circ\text{C}$)

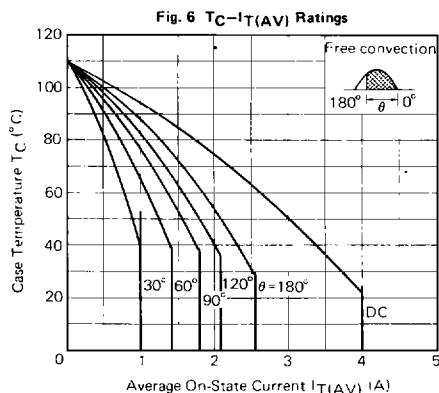
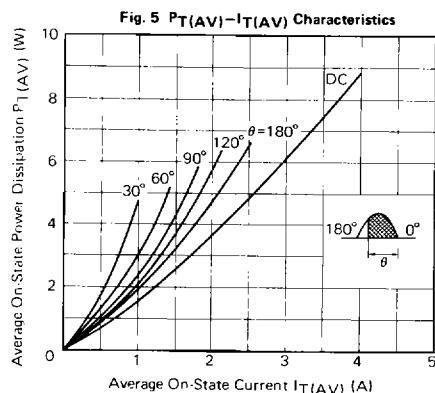
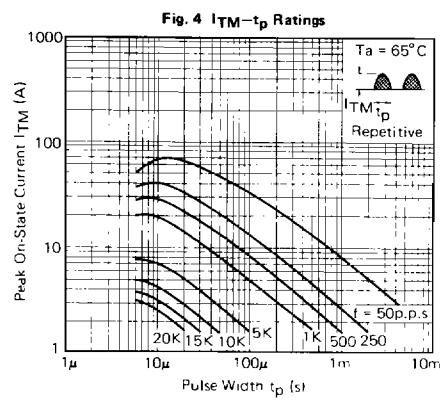
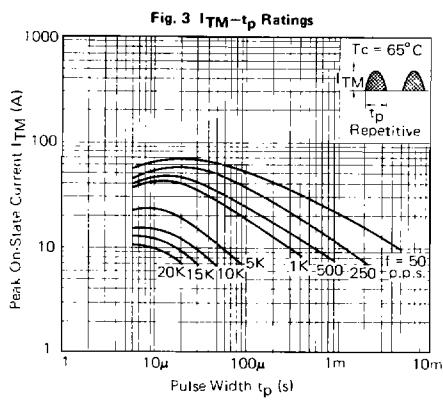
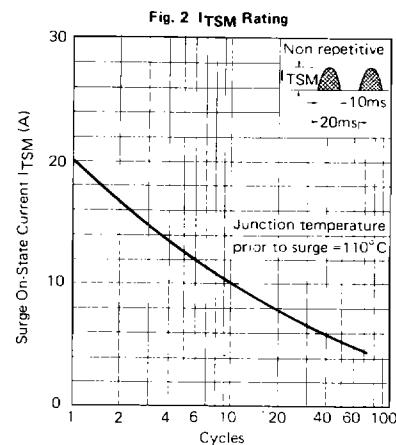
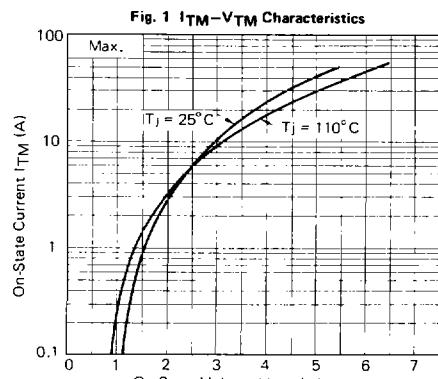
Item	Symbol	Condition	Min.	Typ.	Max.	Unit	Note
Repetitive Peak Reverse Current	I_{RRM}	$V_{RM}=V_{RRM}, T_j=110^\circ\text{C}$ $R_{GK}=1\text{k}\Omega$	—	—	100	μA	
Repetitive Peak Off-State Current	I_{DRM}	$V_{DM}=V_{DRM}, T_j=110^\circ\text{C}$ $R_{GK}=1\text{k}\Omega$	—	—	100	μA	
On-State Voltage	V_{TM}	$I_{TM}=4\text{A}$	—	—	2.2	V	See Fig. 1
Gate Trigger Current	I_{GT}	$V_{DM}=6\text{V}, R_L=100\Omega$ $R_{GK}=1\text{k}\Omega$	—	—	300	μA	See Fig. 8
Gate Trigger Voltage	V_{GT}	$V_{DM}=6\text{V}, R_L=100\Omega$ $R_{GK}=1\text{k}\Omega$	—	—	0.8	V	See Fig. 9
Gate Non-Trigger Voltage	V_{GD}	$V_{DM}=\frac{1}{2}V_{DRM}, T_j=110^\circ\text{C}$ $R_L=100\Omega, R_{GK}=1\text{k}\Omega$	0.2	—	—	V	
Critical Rate-of-Rise of Off-State Voltage	dv/dt	$V_{DM}=2/3V_{DRM}, T_j=110^\circ\text{C}$ $R_{GK}=1\text{k}\Omega$	10	—	—	$\text{V}/\mu\text{s}$	
Holding Current	I_H	$V_D=24\text{V}, R_{GK}=1\text{k}\Omega$	—	—	10	mA	See Fig. 10
Circuit Commutated Turn-Off Time	t_q	$V_{DM}=2/3V_{DRM}, T_j=110^\circ\text{C}$ $dv/dt=10\text{V}/\mu\text{s}, V_R=50\text{V}$ $I_T=2\text{A}, R_{GK}=1\text{k}\Omega$	—	—	15	μs	
Turn-On Time	t_{gt}	$V_{DM}=2/3V_{DRM}, I_{TM}=30\text{A}$ $I_G=5\text{mA}, t_{IG}=5\mu\text{s}$	—	—	2	μs	
Thermal Resistance	$R_{th(j-c)}$	Junction to Case	—	—	10	$^\circ\text{C/W}$	See Fig. 11
	$R_{th(j-a)}$	Junction to Ambient	—	—	75		See Fig. 11

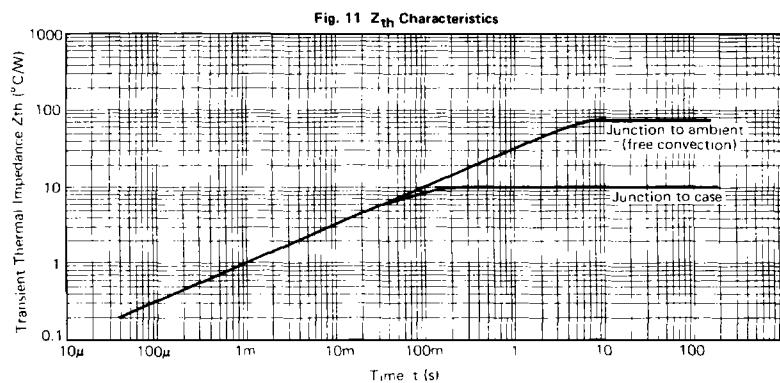
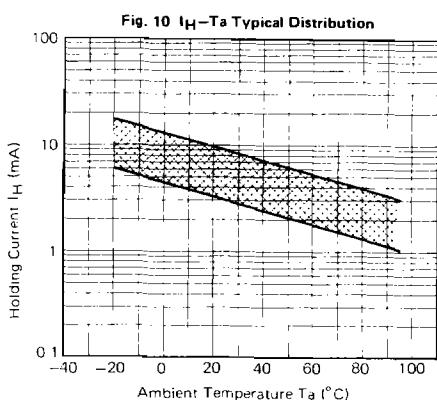
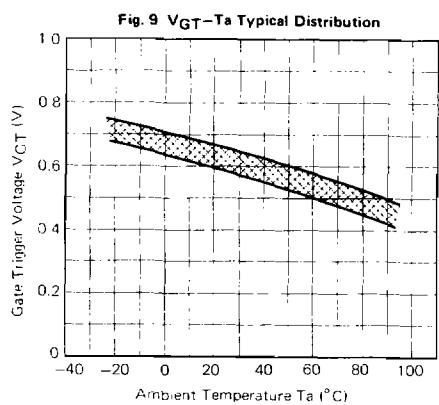
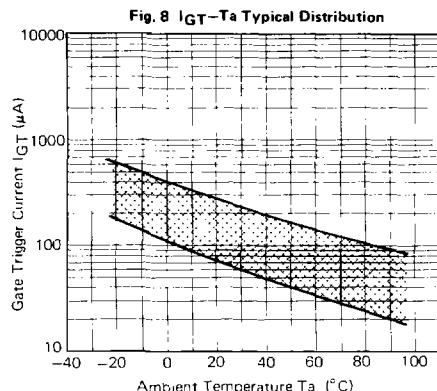
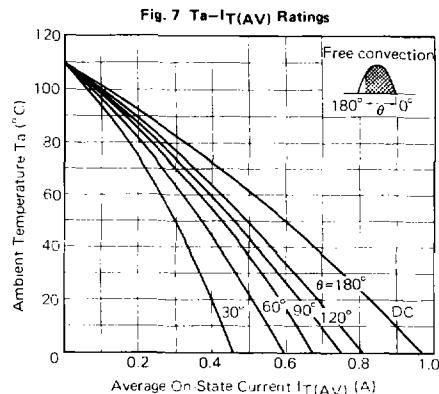
EXAMPLE OF R_{GK} INSERTION

MEASUREMENT CIRCUIT



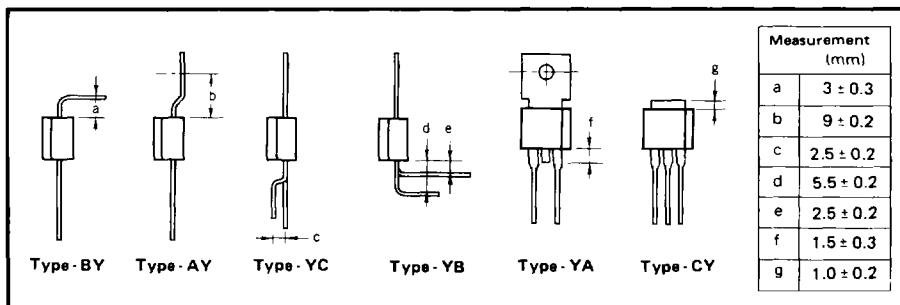
* Inner Resistance V_1 : more than $100\text{k}\Omega$ at $I_{GT} \leq 10\mu\text{A}$
 V_2 : more than $1\text{M}\Omega$ SW open
 E : more than $20\text{k}\Omega$





NOTICE FOR INSTALLATION

1. Electrode leads (especially heat sink tablet) are not granted to be bent because of wet-proof. However in case it is required inevitably, a mechanical stress should not be put on mold. Fix tightly between the mold case and the area to be formed or bent.
2. Electrode leads should not to be bent more than twice over 90°. Avoid the bending within 1.5 mm from the neck of mold case.
3. Special lead and heat tab formings as indicated below are available at an additional cost.



4. The surface of heat sink for thermal radiator is to be smooth without any foreign matter.
5. Suitable torque value is 4 ~ 5 kg.cm.
6. Soldering
 - Recommended solder: PbSu (4 : 6)
Melting point 180°C
 - Dimension from the neck of leads to dipping points 4 ~ 6 mm
 - Soldering temperature and period

250°C less than 5 μ sec.
230°C less than 10 μ sec.